NSN 5962-01-361-4980

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View Online at https://aerobasegroup.com/nsn/5962-01-361-4980

Body Length:

Between 0.540 inches and 0.560 inches

Body Width:

Between 0.438 inches and 0.458 inches

Body Height:

Between 0.100 inches and 0.120 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Pacer special

Features Provided:

Electrostatic sensitive and radiation hardened and selected item and monolithic and erasable and tested to mil-std-883 and w/enable and programmable

Inclosure Material:

Ceramic

Inclosure Configuration:

Leadless flat pack

Output Logic Form:

N-type metal oxide-semiconductor logic

Criticality Code Justification:

Feat

Case Outline Source And Designator:

C-12 mil-m-38510

Terminal Surface Treatment:

Solder

Product Name:

Microcircuits, digital, nmos, 8k x 8 eeprom, monolithic silicon; microcircuit, digital, electrically erasable prom (8k x 8)

Voltage Rating And Type Per Characteristic:

-0.3 volts total supply and 6.0 volts total supply

Time Rating Per Chacteristic:

250.00 nanoseconds access

Memory Device Type:

Eeprom

Special Features:

Electrostatic discharge sens/hardness critical item; selected item, monolithic silicon, nmos floating gate, 64k-bit, 5v elec erasable/programmable eeprom, orig pn 5962-8683004yx

Special Test Features:

Radiation acceptance test

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type	And	Quantity:
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32 leadless

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0